**Vishay Semiconductors** 

RoHS

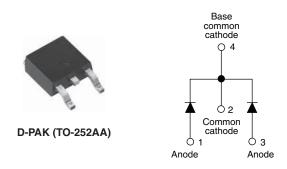
COMPLIANT

HALOGEN

FREE



Ultrafast Rectifier, 2 x 3 A FRED Pt®



PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I <sub>F(AV)</sub>	2 x 3 A				
V <sub>R</sub>	200 V				
V <sub>F</sub> at I <sub>F</sub>	1.0 V				
t <sub>rr</sub> typ.	See Recovery table				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				

#### FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION/APPLICATIONS**

Vishay Semiconductors' 200 V series are the state of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage	V <sub>RRM</sub>		200	V		
Average rectified forward current per device	I <sub>F(AV)</sub>	Total device, rated V <sub>R</sub> , T <sub>C</sub> = 159 °C	6			
Non-repetitive peak surge current	I <sub>FSM</sub>		50	А		
Peak repetitive forward current per diode	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 159 $^\circ\text{C}$	6			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-		
		I <sub>F</sub> = 3 A	-	-	1		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	-	0.9	V	
		I <sub>F</sub> = 6 A	-	-	1.2		
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 125 °C	-	-	1.08		
Deverae leekeese ourrent		V <sub>R</sub> = V <sub>R</sub> rated	-	-	5		
Reverse leakage current I <sub>R</sub>		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	100	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	12	-	pF	
Series inductance	Ls	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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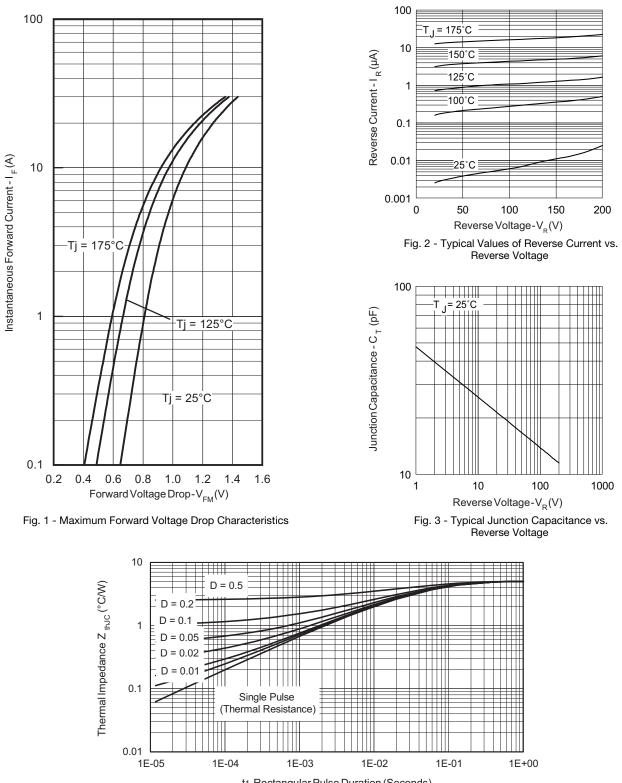
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CON	MIN.	TYP.	MAX.	UNITS		
			/μs, V <sub>R</sub> = 30 V	-	20	35		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	19	-	ns	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 3 A V <sub>R</sub> = 160 V dI <sub>F</sub> /dt = 200 A/μs	-	26	-		
Deels recovery ourrent		T <sub>J</sub> = 25 °C		-	3.1	-	^	
Peak recovery current I <sub>RRM</sub>	IRRM	T <sub>J</sub> = 125 °C		-	4.6	-	A	
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	30	-	nC	
	T <sub>J</sub> = 125 °C		-	60	-	nC		

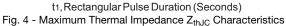
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>	- 65	-	175	°C	
Thermal resistance, junction to case per leg	R <sub>thJC</sub>	-	-	5		
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	-	-	80	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	-	-	-		
Waight		-	0.3	-	g	
Weight		-	0.01	-	oz.	
Mounting torque		6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)	
Marking device		Case style D-PAK 6CWH02FNH			02FNH	





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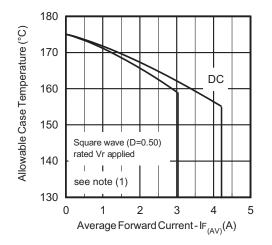


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

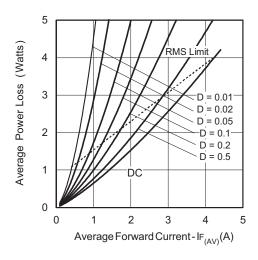


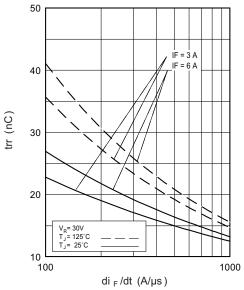
Fig. 6 - Forward Power Loss Characteristics

#### Note

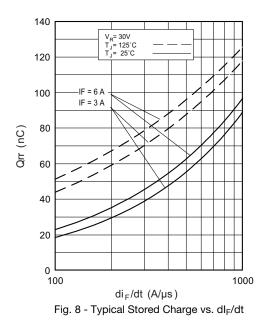
 $\begin{array}{ll} \mbox{(1)} & \mbox{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{th,JC}; \\ Pd = \mbox{Forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = \ \mbox{Inverse power loss} = V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = \ \mbox{Rated} \ V_R \end{array}$ 

## VS-6CWH02FNHM3

### **Vishay Semiconductors**







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## VS-6CWH02FNHM3



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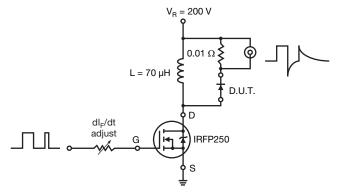
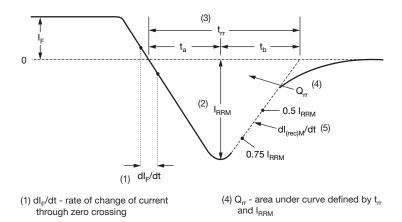


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

### Vishay Semiconductors

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#### **ORDERING INFORMATION TABLE**

Device code	VS-	6	с	w	н	02	FN	TRL	н	М3
		2	3	4	5	6	7	8	9	10
	1		hay Sen			oduct				
	2		rent rati							
	3		nter tap	•	ation					
	4		kage id							
			= D-PAK	-						
	5		Hyperfa		-					
	6		tage rati		= 200 V)					
	7	- FN	= TO-28	52AA						
	8	- • N	one = T	ube (50	pieces)					
		• T	R = Tap	e and re	el					
		• TI	RL = Ta	pe and r	eel (left	oriente	d)			
		• TI	R = Ta	pe and	reel (rig	ht orien	ted)			
	9	- H=	AEC-Q	101 qua	lified					
	10	- Env	vironmer	ntal digit	:					
		М3	= Halog	en-free,	RoHS-	complia	nt, and	termina	tions lea	ad (Pb)-f

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-6CWH02FNHM3	75	3000	Antistatic plastic tube			
VS-6CWH02FNTRHM3	2000	2000	13" diameter reel			
VS-6CWH02FNTRRHM3	3000	3000	13" diameter reel			
VS-6CWH02FNTRLHM3	3000	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				



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